PCN Numb	per:	2023013	31001.2				ate:	February 01, 2023		
Title:	Adding TI CD Assembly and	-PR as add Test site	R as additional wafer probe (EWS) site and TI CDAT as additional est site for select devices							
Customer	Contact:	PCN M	<u>lanager</u>			Dept:		Quality Services		
Proposed	1 st Ship Date	Aug 0	1, 2023	1, 2023 Samplaccep			ests til:	Mar 03, 2023*		
*Sample re	quests receive	d after Ma	ar 03, 2023	will not	be supp	orted.				
Change Ty	vpe:									
🛛 Assem	bly Site		Design				Wafer	Bump Site		
Assem	bly Process		Data S	heet		<u> </u>	Wafer	Bump Material		
Assem	bly Materials			imber c	hange		Wafer	Bump Process		
	nical Specificat	ling		te			Wafer	Fab Site		
	g/Shipping/Lac	enng		000055			Wafer	Fab Process		
			PCN	Detail	5		Waren	10011000000		
Descriptio	n of Change:		T CIT		5					
Toyac Instr		orated ba	a gualified C		additio	nalara		S) cito and TI		
	Interits Incorp	orateu na		D-PR ds	listed by	alow in	be (EW)	duct affected		
section. No	o material diffe	rences be	est site for t	nbly site			the plot			
				inory orec						
		C	Current:			N	lew:			
Prob	e Site (EWS)	TI Clar	k (CLARK-PR)	7	TI Cheng	du (CD-	PR)		
Fina	I Test Site (FT)	UTAC	(UTL2)		7	TI Chengdu (CD-AT)				
Test covera	age, insertions,	condition	ns will remain	n consis	tent wit	h curre	nt testir	ng.		
Reason fo	r Change:									
Enable add	itional probe ca	apacity to	support hig	h volum	e ramps	5.				
Continuity	of Supply	. ,	11 5							
Anticipate	d impact on I	orm, Fit	, Function,	Qua lity	or Rel	ia bility	(posit	ive / negative):		
None										
Impact on	Environmen	tal Rating	gs							
Checked bo change. If ratings.	oxes indicate tl below boxes ar	ne status (e checked	of environme d, there are	ental rat no chan	ings fol ges to t	lowing i he asso	mpleme ciated e	entation of this environmental		
R	oHS	RE	EACH	G	reen St	tatus		IEC 62474		
🛛 No Cha	nge	🛛 No Cha	ange	🛛 🖾 No	o Chang	le	1 🛛	No Change		
Changes t	o product ide	ntificatio	on resulting	from t	his PCI	N:				
Assembly	Site		-							
UTAC	/	Assembly	Site Origin (22L)	ASO: N	IS2				
TI Chengdu	u /	Assembly	Site Origin (22L)	ASO: C	DA				
Sample pro	duct shipping	label (not	actual produ	uct label)					
MADE IN: 2DC: MSL '2 /20 MSL '2 /20 MSL '2 /20 MSL 1 /23 OPT: ITEM: LBL: 5	AS IENTS 20: 50C/1 YEAR SEA 55C/UNLIM 03/ A (L)T0:1	G4 G4 ^{L DT} 29/04 750			1P) SN (Q) 2(31T) L 4W) TK 2D) REV 20L) CS 22L) AS	174LS0 000 07:39 (11) 0:5HE 0:5HE	(D) (59047 7523 (21L) C (23L) A	0336 MLA 483512 005917 CCO:USA ACO: MYS		

Texas Instruments Incorporated

TI Information - Selective Disclosure PCN# 20230131001.2

TPS25850QRPQRQ1	TPS25855QRPQRQ1	TPS25862QRPQRQ1	TPS25869QRPQRQ1
TPS25851QRPQRQ1	TPS25858QRPQRQ1	TPS25864QRPQRQ1	
TPS25852QRPQRQ1	TPS25859QRPQRQ1	TPS25865QRPQRQ1	
TPS25854QRPQRQ1	TPS25860QRPQRQ1	TPS25868QRPQRQ1	

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approved 17-Dec-2020

Product Attributes

Attributes	Qual Device: <u>TPS552882QRPMRQ1</u>	Qual Device: <u>TPS55288QRPMRQ1</u>	QBS Process Reference: <u>TPS61378QWRTERQ1</u>		
Automotive Grade Level	Grade 1	Grade 1	Grade 1		
Operating Temp Range	-40 to +125 C	-40 to +125 C	-40 to +125 C		
Product Function	Pow er Management	Pow er Management	Pow er Management		
Wafer Fab Supplier	RFAB	RFAB	RFAB		
Die Revision	A1	A2	A0		
Assembly Site	CDA T	CDAT	CDA T		
Package Type	QFN/ SON	QFN/ SON	QFN/ SON		
Package Designator	RPM	RPM	RTE		
Ball/Lead Count	26	26	16		

- QBS: Qual By Similarity

- Qual Device TPS552882QRPMRQ1 and TPS55288QRPMRQ1 are qualified at LEVEL2-260CG

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Mi n Lo t Qt y	SS / Lo t	Test Name / Condition	Duration	Qual Device: TPS552882QRPMR Q1	Qual Device: TPS55288QRPMR Q1	QBS Process Reference: <u>TPS61378QWRTE</u> <u>RQ1</u>
Test Gr	roup	A – Accele	rated	Enviro	onment Stress T	ests			
PC	A 1	JEDEC J-STD- 020 JESD2 2-A113	3	77	Automotive Preconditioni ng	Level 2- 260C	3/AII/0	-	3/AII/0
HAST	A 2	JEDEC JESD2 2-A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0	-	3/231/0
UHAS T	A 3	JEDEC JESD2 2-A118	3	77	Unbiased HAST, 130C/85% RH	96 Hours	3/231/0	-	3/231/0

тс	A 4	JEDEC JESD2 2-A104 and Append ix 3	3	77	Temperature Cycle, - 65/150C	500 Cycles	3/231/0	-	3/231/0
PTC	A 5	JEDEC JESD2 2-A105	1	45	Pow er Temp. Cycle, - 40/125C	1000 Cycles	1/45/0	-	1/45/0
HTSL	A 6	JEDEC JESD2 2-A103	1	45	High Temp. Storage Bake, 175C	500 Hours	3/231/0	-	3/231/0
Test G	roup	B – Accele	rated	Lifetir	ne Simulation To	ests			
HTOL	В 1	JEDEC JESD2 2-A108	3	77	Life Test, 150C	408 Hours	3/231/0	-	3/231/0
ELFR	В 2	AEC Q100- 008	3	80 0	Early Life Failure Rate, 125C	48 Hours	1/800/0	-	3/2400/0
Test G	roup	C – Packag	je Ass	sembl	y Integrity Tests				
WBS	C 1	AEC Q100- 001	1	30	Bond Shear (Cpk>1.67)	Wires	N/A	N/A	3/90/0
WBP	C 2	MIL- STD88 3 Method 2011	1	30	Bond Pull (Cpk>1.67)	Wires	N⁄A	N⁄A	3/90/0
SD	C 3	JEDEC JESD2 2-B102	1	15	Solderability >95% Lead Coverage	Pb-Free	1/15/0	-	1/15/0
SD	C 3	JEDEC JESD2 2-B102	1	15	Solderability >95% Lead Coverage	Pb	1/15/0	-	1/15/0
PD	C 4	JEDEC JESD2 2-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)		3/30/0	-	3/30/0
SBS	C 5	AEC Q100- 010	3	50	Solder Ball Shear (Cpk>1.67)	Post HTSL/Bu mp	N⁄A	N/A	N/A
Ц	C 6	JEDEC JESD2 2-B105	1	50	Lead Integrity	Leads	N⁄A	N⁄A	N/A
Test G	roup	D – Die Fak	bricati	on Re	liability Tests				
EM	D 1	JESD6 1	-	-	Electromigrati on		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-
TDDB	D 2	JESD3 5	-	-	Time Dependant Dielectric Breakdow n		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-
HCI	D 3	JESD6 0 & 28	-	-	Hot Injection Carrier		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-
NBTI	D 4	-	-	-	Negative Bias Temperature Instability		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-

SM	D 5	-	-	-	Stress Migration		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-			
Test Group E – Electrical Verification Tests												
НВМ	E 2	AEC Q100- 002	1	3	ESD - HBM	3000 V	1/3/0	1/3/0	1/3/0			
CDM	E 3	AEC Q100- 011	1	3	ESD - CDM	1000 V	1/3/0	1/3/0	1/3/0			
LU	E 4	AEC Q100- 004	1	6	Latch-up	(Per A EC- Q100- 004)	1/6/0	1/6/0	1/6/0			
ED	E 5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold test	3/90/0	1/30/0	3/90/0			

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I) : -40°C to +85°C E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approved 09-Dec-2022

Product Attributes

Attributes	Qual Device: TPS258XXQRPQRQ1	QBS Reference: <u>TPS61378</u> Q <u>WRTERQ1</u>	QBS Reference: <u>TPS25772B00QRQLRQ1</u>	QBS Reference: <u>TPS25850</u> QRPQRQ1	QBS Reference: <u>TPS25850</u> Q <u>RP</u> Q <u>RQ1</u>
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Power Management	Power Management	Power Management	Power Management	Power Management
Wafer Fab Supplier	RFAB	RFAB	RFAB	RFAB	RFAB
Assembly Site	CDAT	CDAT	CDAT	UTL1	CDAT
Package Group	QFN-HR	QFN	QFN-HR	QFN-HR	QFN-HR
Package Designator	RPQ	RTE	RQL	RPQ	RPQ
Pin Count	25	16	29	25	25

QBS: Qual By Similarity. Product Family is qualified at LEVEL2-260C.

Each product in the family passed Yield Analysis represented in TPS258XXQRPQRQ1 device matrix.

TPS25851QRPQRQ1	TPS25860QRPQRQ1
TPS25852QRPQRQ1	TPS25862QRPQRQ1
TPS25854QRPQRQ1	TPS25864QRPQRQ1
TPS25855QRPQRQ1	TPS25868QRPQRQ1
TPS25859QRPQRQ1	TPS25869QRPQRQ1

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: <u>TPS25862</u> Q <u>RP</u> Q <u>RQ1</u>	QBS Reference: <u>TPS61378</u> QWRTERQ1	QBS Reference: <u>TPS25772B00</u> QRQLRQ1	QBS Reference: <u>TPS25850</u> Q <u>RP</u> Q <u>RQ1</u>	QBS Reference: <u>TPS25850</u> QRPQRQ1
Test Group A	- Acceler	ated Environment Str	ess Tests									
PC	A1	JEDEC J- STD-020 JESD22A113	3	77	Preconditioning	MSL2 260C	1 Step	-	3/0/0	3/0/0	3/0/0	1/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours		3/231/0	3/231/0	3/231/0	1/77/0
AC/UHAST	A3	JEDEC JESD22A102/JEDEC JESD22A118	3	77	Autoclave	121C/15psig	96 Hours	-	-	3/231/0	3/231/0	1/77/0
AC/UHAST	A3	JEDEC JESD22A102/JEDEC JESD22A118	3	77	Unbiased HAST	130C/85%RH	96 Hours		3/231/0			
тс	A4	JEDEC JESD22A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0	1/77/0
РТС	A5	JEDEC JESD22- A105	1	45	РТС	-40/125C	1000 Cycles	-	1/45/0	1/45/0	1/45/0	1/45/0
TSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	-	-	1/77/0	1/45/0	1/45/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours	-	3/135/0	-	-	
Test Group B	- Acceler	ated Lifetime Simulati	ion Tests									
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	125C	1000 Hours	-	-	3/231/0	1/77/0	1/77/0

HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C	408 Hours		3/231/0	-				
ELFR	B2	AEC Q100008	1	77	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-	-	-		
Test Group C - Package Assembly Integrity Tests														
WBS	сі	AEC Q100001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	-	3/90/0	-	-	-		
WBP	cz	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	-	3/90/0		-			
SD	сз	JEDEC JESD22B102	1	15	PB Solderability	>95% Lead Coverage			1/15/0	1/15/0		1/15/0		
SD	сз	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-		1/15/0	1/15/0	-	1/15/0		
PD	C4	JEDEC JESD22B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	-	3/30/0			1/10/0		
Test Group D	- Die Fab	rication Reliability Te	ests											
EM	D1	JESD61			Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		
SM	D5	-	-		Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		

Test Group E	Test Group E - Electrical Verification Tests													
ESD	E2	AEC Q100002	1	3	ESD HBM	-	4000 Volts	-	1/3/0	1/3/0	1/3/0	-		
ESD	E3	AEC Q100011	1	3	ESD CDM		1500 Volts	-	1/3/0	1/3/0	1/3/0	-		
LU	E4	AEC Q100004	1	6	Latch-Up	Per AEC Q100- 004	-	-	1/6/0	1/6/0	1/6/0	-		
ED	E5	AEC Q100009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	1/30/0	3/90/0	-		1/30/0		

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV:150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C

Grade 3 (or I) : -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold : HTOL, ED

Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

ZVEI ID reference: SEM-PA-18, SEM-TF-01

TI Information - Selective Disclosure

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail
WW Change Management Team	<u>PCN ww admin team@list.ti.com</u>

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